# NSN 5962-01-367-1288

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### **Body Length:**

Between 1.050 inches and 1.070 inches

## **Body Width:**

Between 0.300 inches and 0.320 inches

## **Body Height:**

Between 0.190 inches and 0.210 inches

## **Maximum Power Dissipation Rating:**

1.2 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### End Application:

Eo lorops

#### Features Provided:

Bipolar and programmed and monolithic and electrostatic sensitive

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

### Output Logic Form:

Bipolar metal-oxide semiconductor

### Input Circuit Pattern:

16 input

#### **Criticality Code Justification:**

Feat

## Case Outline Source And Designator:

D-8 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Microcircuit, programmed

#### Voltage Rating And Type Per Characteristic:

-0.5 volts total supply and 7.0 volts total supply

#### Memory Device Type:

Pal

### **Special Features:**

Esd; altered item programmed using 67268/5962-8515509rx using file 1055\_u29.Jed with check sum o72e

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

20 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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